

## AFBR-S50MV85G

# Time-of-Flight Sensor Module for Distance and Motion Measurement



### Description

The Broadcom<sup>®</sup> AFBR-S50MV85G is a multipixel optical distance and motion measurement sensor module based on the optical Time-of-Flight principle. The technology has been developed with a special focus on applications that need the highest speed and accuracy at medium distance ranges, with a small size and very low power consumption.

Due to its ambient light suppression, use in outside environments is possible in sunlight. The sensor accurately measures white, black, colored, as well as metallic and retroreflective surfaces.

The module has an integrated infrared laser light source and an internal clock source. A single 5V power supply is required. Data is transferred using a digital Serial Peripheral Interface (SPI) using standard 3.3V CMOS levels. For system health monitoring, a reference pixel is used in addition to the integrated voltage and temperature sensors.

Frame rates of up to 3 kHz are supported, depending on the microcontroller, the data streaming mode, and the number of evaluated pixels. For frame rates up to 100 Hz, a dual-frequency mode (2f) is used to achieve an unambiguous range of up to 100m.

### **Specifications**

- Single voltage supply of 5V
- Typical current consumption of 33 mA
- Integrated 850-nm laser light source
- Typical optical peak output power of 40 mW
- Typical optical average output power < 0.6 mW</li>
- Receiver with 32 pixels
- Field-of-view per pixel of 1.55° × 1.55°
- Transmitter beam width of 4° × 4° to illuminate typically
   7 to 16 pixels (3 pixels per dimension)
- Distance range up to 10m and beyond
- Operation temperature (ambient): -20°C to +70°C
- SPI digital interface up to 25 MHz
- Size without pins:  $12.4 \times 7.6 \times 7.9 \text{ mm}^3 (L \times W \times H)$

#### **Features**

- Very fast measurement rates of up to 3 kHz
- Operation up to 200 klx
- Multipixel for 3D motion detection
- Integrated calibrated clock source
- Accuracy error typically below ±1%
- Unambiguous range up to 100m in 2f mode
- Reference pixel for system health monitoring
- Laser Class 1 eye safe ready

### **Applications**

- Distance measurement
- Human machine interfaces
- Robotics
- Automation and control
- Security surveillance
- Inventory monitoring
- Augmented reality

### **Mechanical Dimensions**

#### Figure 1: Module Side and Top View, Dimensions in mm







#### Figure 2: Module Bottom View, Dimensions in mm



#### NOTES:

1) Dimensions are in millimeters.

2) Nominal values rounded to two decimal places -

Suppression of following zeros.

3) PCB outer dimension

4) Housing outer dimension

5) Each pin head consists of a metal ring with a diameter of 1.0mm at the insertion point into the sensor PCB (Figure 2).

## **Functional Description**

The integrated Time-of-Flight (ToF) sensor module is equipped with an 850-nm vertical-cavity surface-emitting laser (VCSEL) for invisible infrared illumination. The integrated lens for the receiver has a clear aperture of 6 mm in diameter and a Field-of-View (FoV) of 1.55° per pixel.

Figure 3: Block Diagram of the AFBR-S50MV85G



The transmitter is aligned with the receiver to simultaneously illuminate between 7 and 16 pixels, depending on the distance and reflectivity of the target object and the settings of the software pixel binning algorithm. The binning algorithm can be configured by the user to either allow for more pixels for 3D applications or optimize settings for a highly precise 1D distance measurement, depending on the actual application. In addition, the system compensates for parallax errors for very near distances. This allows the module to achieve a good pixel intensity for distance measurements over the whole measurement range, as well as deliver context information for the system. Context information includes motion, speed, tilt angles, or lateral alignment precision for small targets or features.

The maximum distance range for detecting black targets with 8% remission is up to 10m within an indoor environment. For harsh outdoor conditions under bright sunlight (for example, 100 klx with a typical midday sunlight spectrum AM 1.5), the maximum distance range for detecting black targets with 8% remission is reduced to less than 7m. If dual-frequency mode is enabled, the useful distance substantially exceeds 10m for bright or highly reflective targets. This mode is supported for frame rates up to 100 Hz.

There is no processor with firmware on the module. All hardware configuration, calibration, and measurement steps are performed by an external microcontroller using the ToF driver software, which extracts both distance and amplitude values of all used pixels on a per-frame basis. The driver software is available as a library independent of the underlying hardware platform within the ARM Cortex-M family. Example software applications, such as extraction and graphical display of distance and direction, are provided with the software development kit (SDK).

The ready-to-run binaries of the ToF driver software include an application programming interface (API), which allows the user to configure and customize the device operation, and are provided free-of-charge under a generic end-user license agreement. Additionally, a reference implementation utilizing the driver software binaries with an Arm Cortex M0/M0+, M1, M3, and M4+ 32-bit platform is provided with an open source SDK under the GNU GPL license for evaluation and reference purposes. For detailed instructions on how to install and run the kit, refer to the getting started document.

The module uses an integrated factory-calibrated and temperature-compensated RC oscillator as well as an all-digital PLL for highly precise clock generation. The module is factory calibrated; however in certain applications (cover glass), an additional customer calibration is required. A suitable compensation and calibration functionality is provided along with the software driver and application software package.

## **Description of the Time-of-Flight Sensor ASIC and Detector Matrix**

The ToF sensor ASIC includes all required building blocks for clock and supply generation out of a single supplied voltage, analog and digital signal processing, and a laser driver. The receiver sensor consists of 32 pixels, partitioned into eight rows and four lines with a hexagonal structure. The ToF drive stage allows both driving laser light sources with variable threshold and modulation currents as well as LEDs for up to 55-mA peak current, depending on module configuration.





Figure 5: Hexagonal Structure of Sensor Matrix, Dimensions in µm



Figure 6: Field-of-View (FoV) Description of the Sensor



## **Detailed Module Pin Description and Operation**

The housing/device includes 4.3-mm long pins with a 1.0-mm-wide conductive ring at its head and is designed for wave soldering. Reflow soldering is not allowed. Shortcuts with the conductive ring at the pin head must be avoided. Because the housing is not hermetic and uses venting holes for pressure balance, no wash or flux clean is allowed. Operation in humid, noncondensing environments is possible; see Table 4.

The housing provides a robust mechanical, thermal, and electrical connection to the customer PCB. The module uses a 5.0V supply, which is split up into a laser and a sensor supply rail. Separate local blocking and filtering is recommended to avoid electrical crosstalk from the laser into the sensor supply. All data sheet performance values are based on the internal clock source only. The pins are described in the following table.

Pin Number	Name	Pin Type	Buffer Type	Description
1	SPI_CLK	I	3.3V CMOS	SPI Clock Input for SPI interface clock up to 25 MHz using standard 3.3V CMOS levels.
2	SPI_MOSI	I	3.3V CMOS	SPI Slave Data Input using standard 3.3V CMOS levels.
3	SPI_MISO	0	3.3V, PP	SPI Slave Data Output (Push-Pull) using standard 3.3V CMOS levels with a drive strength of 8 mA.
4	IRQ_n	0	3.3V, OD	Active Low Interrupt Output (Open Drain). Measurement-ready output (Open Drain), using standard 3.3V CMOS levels with a drive strength of 4 mA with an internal pull-up of 50 k $\Omega$ . An external pull-up to 3.3V using a 10-k $\Omega$ resistor is recommended.
5	GNDL	GND	—	Laser Driver Ground, connect with Sensor GND on the PCB.
6	VDDL	PWR	—	Laser Anode Supply, connect with a ferrite bead to 5V and buffer with 10 $\mu\text{F}/$ 100 nF versus GNDL.
7	GND	GND	—	Sensor Ground, connect to a GND plane on the PCB.
8	VDD	PWR	—	Sensor Supply, connect to 5V and buffer with 10 $\mu F/100$ nF versus GND.
9	GND	GND	—	Sensor Ground, connect to a GND plane on the PCB.
10	CLK+	I/O	3.3V/LVDS	Optional: Clock input/output, single-ended/differential. Reference clock output; do not connect if not used; differential or single-ended.
11	CLK-	I/O	LVDS	Optional Clock input/output, differential. Reference clock output; do not connect if not used; differential only.
12	Test	NU	—	Test pin for factory usage, do not connect.
13	VDD	PWR	—	Sensor Supply, connect to 5V and buffer with 10 $\mu F/100$ nF versus GND.
14	GND	GND	_	Sensor Ground, connect to a GND plane on the PCB.
15	SPI_CS_n	I	3.3V CMOS	SPI Chip Select (active-low) using standard 3.3V CMOS levels, internal pull-up of 50 k $\Omega$ .

#### Table 1: I/O Pin Configuration

## **Absolute Maximum Ratings and Regulatory Compliance**

Stresses in excess of the absolute maximum ratings can cause catastrophic damage to the device. Limits apply to each parameter in isolation, all other parameters having values within the recommended operation conditions. Exposure to the absolute maximum ratings for extended periods can adversely affect device reliability.

#### Table 2: Absolute Maximum Ratings

Description	Symbol	Min.	Тур.	Max.	Units	Notes
Supply Voltage Sensor	VDD	-0.5		5.5	V	_
Supply Voltage Laser	VDDL	-0.5	_	VDD + 0.5V	V	а
Storage Temperature Range	T <sub>stor</sub>	-40	—	95	°C	—
Maximum Operating Temperature Range	T <sub>amb</sub>	-20	—	70	°C	b
Lead Soldering Temperature	T <sub>sold</sub>	—	—	260	°C	с
Lead Soldering Time	t <sub>sold</sub>	_		10	S	С
ESD Protection, Human Body Model	ESD_HBM	-1500	_	1500	V	d
Ambient Light Illuminance at Starting, Powering Up, and Resetting of Device	Ev	_	_	100	klx	e

a. During power-up, VDDL and all other signal pins must not exceed VDD by more than 0.5V.

b. Operating the product outside the maximum rated ambient operating temperature range will compromise its reliability and may damage the product. Ambient air temperature is defined as the temperature measured with the thermocouple placed close to the sensor.

c. The module is Pb-free wave solderable (no clean): JESD22-B106D. The moisture sensitivity level is 3.

d. Human Body Model (HBM): JEDEC JS-001-2012.

e. 100 klx (Spectrum AM 1.5) measured on a 90% remission target.

#### Table 3: Regulatory Compliance

Feature	Test Method	Performance and Comments
Electrostatic Discharge (ESD) to the Electrical Pins	JEDEC JS-001-2012	Withstands up to 1500V HBM applied between electrical pins.
RoHS I and II Compliance	RoHS Directive 2011/65EU Annex II	_
REACH Compliance	EC No 1907/2006	_
UL-94 Flammability	UL-94V-0	—
Eye Safety	Tested according to the following standards:	Class 1 <sup>a</sup>
	<ul> <li>EN 61010-1:2010</li> <li>EN 60825-1:2014</li> <li>EN 06825-2:2004+A1+A2</li> </ul>	

a. Laser Class 1 operation depends on correct system integration and software configuration. Without the correct configuration or before the integration has been completed, the module can emit at higher levels and is rated as a Laser Class 3B device.

#### Figure 7: Laser Safety Warning Sign for Unrecommended/Nondefault Operation



## **Operating Conditions and Electrical Characteristics**

 Table 4: Recommended Operating Conditions

Description	Symbol	Min.	Тур.	Max.	Units	Notes
Supply Voltage Sensor	V <sub>DD</sub>	4.5	5	5.5	V	а
Supply Voltage Laser (Anode)	V <sub>DDL</sub>	4.5	5	5.5	V	а
Maximum Ripple of Supply Voltage Sensor	V <sub>PP</sub>	—	—	100	mV <sub>pp</sub>	b
Maximum Ripple of Supply Voltage Laser	V <sub>PPL</sub>	—	—	100	mV <sub>pp</sub>	b
Operation Temperature Range	T <sub>amb</sub>	-20	25	70	°C	—
Relative Humidity, Non-Condensing	RH	—	—	85	%	_

a. For operation over the full temperature range, it is recommended to limit the range from 4.75V to 5.25V.

b. Ripple to be measured with a bandwidth of at least 200 MHz.

#### **Table 5: Electrical Characteristics**

Description	Symbol	Min.	Тур.	Max.	Units	Notes	
SPI Slave Interface Clock Frequency	f <sub>SPI</sub>	1	12	25	MHz		
Low Level Input Voltage	VIL	-0.3		0.8	V		
High Level Input Voltage	VIH	2	_	3.6	V	_	
Low Level output Voltage	VOL	_	—	0.8	V	—	
High Level Output Voltage	VOH	2.8	—	_	V	—	
Output Current of SDO	I <sub>SDO</sub>	3	—	8	mA	—	
Peak Laser Current	I <sub>VDDL_peak</sub>	_	55	60	mA	—	
Average Laser Current	<i<sub>VDDL&gt;</i<sub>	0.1	1	2	mA	а	
Average Sensor Current	<i<sub>VDD&gt;</i<sub>	_	32	40	mA	_	
Active System Power Consumption	P <sub>diss,total</sub>	_	165	230	mW	b	
Power-Up Time	t <sub>poweron</sub>	_	—	1	ms	с	
Initialization Time	T <sub>init</sub>		300	_	ms	d	

a. Assumes Laser Class 1 operation.

b. Assumes a constantly active device and no use of standby modes between two frames.

c. Time until the device is ready to accept commands.

d. Initialization/boot-up time from first access to start of measurement.

## **Optical Module Performance Summary**

The AFBR-S50MV85G is one of the most flexible Time-of-Flight measuring modules available in the market. It provides excellent sensitivity combined with a very wide dynamic range and ambient light suppression, and support for short measurement cycles. In contrast to typical laser ranging sensors, several pixels are operated simultaneously to allow for 3D object movement extractions. Of course all those performance parameters typically cannot be optimized at the same time. Therefore, useful configurations for certain applications are supported and can be selected on-the-fly in the driver software in order to allow for a combination and time interleaved operation of different modes.

Unless otherwise specified, all parameters in the following table are applicable for all operating conditions.

#### Table 6: Optical and Sensor Characteristics

Description	Symbol	Min.	Тур.	Max.	Units	Notes
Emission Wavelength	λ	840	850	865	nm	
Beam Divergence 1/e2 Full Width	$\Theta_{full}$	3.5	4.0	4.5	0	а
Squint Angle Rx FoV Horizontal	$\Phi_{Rx}$	_	2.7	_	٥	а
Light Spot Diameter at 1000-mm Distance	D <sub>1000</sub>	60	70	80	mm	b
Pixel FoV at 100-mm Distance	Dpix <sub>100</sub>	_	2.7	—	mm	—
Pixel FoV at 1000-mm Distance	Dpix <sub>1000</sub>	_	27	—	mm	—
Pixel FoV at 10,000-mm Distance	Dpix <sub>10000</sub>	_	270	_	mm	
Number of Actively Illuminated Pixels	#Pix <sub>illum</sub>	5	7	16	#	_
Number of Available Pixels	#Pix	_	32	_	#	_
Pitch of Detector Pixels	d <sub>Pix</sub>	_	150	—	μm	—
Bit Clock	f <sub>bit</sub>	48	96	192	MHz	_
Actual Laser Pulse Length (Pattern)	t <sub>pulse</sub>	10.4	20.8	41.6	ns	_
Analog Integration Time per Phase	t <sub>int</sub>	0.01	10	40	μs	с
Frame Rate (All Pixels, max. t <sub>int</sub> 20 µs)	f <sub>frame_max</sub>	5	100	1000	Hz	d, e
Frame Rate (16 pixels, max. t <sub>int</sub> 10 µs)	f <sub>frame_max</sub>	5	100	2000	Hz	d, f
Frame Rate (8 Pixels, t <sub>int</sub> max. 5 μs)	f <sub>frame_max</sub>	5	100	3000	Hz	d, g
Measurement Range	d <sub>meas</sub>	10	_	10,000	mm	h
Distance Resolution	Δd <sub>res</sub>	_	0.1	—	mm	_
Precision	σ	0.5	10	—	mm	i
Absolute Accuracy of Zero Point (Offset)	∆d <sub>abs</sub>	-10		10	mm	—
Relative Distance Accuracy	∆d <sub>rel</sub>	_	±1	—	%	j
Ambient Light Illuminance Suppression	E <sub>AL</sub>	_	100,000	200,000	lx	k
Eye Safety IEC 60825-1:2014	Class	_	1	—	_	I

a. Using optics and laser optimized for the simultaneous use of typically 7 pixels.

b. See Figure 21 for spot diameters at other distances.

c. Automatically configured by the API, the analog integration is set to maximize signal amplitude by maintaining Laser Class 1.

d. The minimum value applies to device software versions v1.3.5 and below. Higher versions support lower frame rates.

e. Maximum 40-ns pulses, all pixels active, SPI clock minimum of 12 MHz, analog integration time limited by eye safety.

f. Maximum 40-ns pulses, 16 pixels active, SPI clock minimum of 21 MHz, analog integration time limited by eye safety.

g. Maximum 40-ns pulses, 8 pixels active, SPI clock minimum of 21 MHz, analog integration time limited by eye safety.

h. Maximum measurement range depends on target remission, ambient light, and sensor configuration (see Figure 12 and Figure 18).

i. Depending on the remission and distance of the object, the pulse length, and the integration time typical value for 8% remission at 4m distance with about 1-klx ambient light at 25°C and a frame rate of 25 Hz (see Figure 8).

j. Best accuracy values are achieved in short range mode and individual crosstalk calibration (API) for Broadcom default pixel binning settings with amplitudes larger than 100 LSB at 25°C 1-klx background light.

k. Maximum value is 200 klx (AM 1.5) on a 45% remission target or 100 klx on a 90% remission target.

 Laser class depends on the software configuration; default operation is for IEC Laser Class 1. The customer must follow and fulfill the Broadcom SW and HW design recommendations to achieve Laser Class 1. Without the correct configuration or before the integration has been completed, the module can emit at higher levels and must be rated as a Laser Class 3B device.

## **Example Characteristics**

To show the dependencies of measured distance repeatability and maximum detectable distance, a set of example characteristics are presented in the graphs on the following pages. Repeatability error is referred to as precision. Precision values and the maximum usable distance depend on the target reflectivity or remission (undirected reflectivity with Lambertian characteristics), in combination with an ambient light illumination of the target.

The average output power is selected to meet Laser Class 1 eye safety. The laser pulse lengths can be chosen to allow for either of the following:

- High precision and accuracy (short range mode) or
- Maximum sensitivity at the expense of larger distance noise (long range mode)

The native unambiguous range is 6.25m for short range mode and 12.5m for long range mode. It is extended by a factor of eight to 50m and 100m, respectively, if dual-frequency mode is selected. Dual-frequency mode is supported for frame rates up to 100 Hz. By default, short range mode is selected with dual-frequency mode enabled. Figure 8 through Figure 11 and Figure 14 through Figure 17 show the typical precision values as a function of target distance and target remission (4% for deep black, 8% for metallic black, 18% for gray, and 90% for white) for both range modes. By changing the sensor configuration in the software, this limit can be further increased if required, at the expense of precision and maximum possible frame rates. The following general trends apply to all scenarios:

Precision scales with the square root of the frame rate. Because the frame rate determines the number of analog
measurements per frame and not the length of each individual analog measurement, it does not directly affect the
detection limit or maximum usable range.

For example, lowering the frame rate from 100 Hz to 25 Hz will reduce the precision error by a factor of two. See Figure 20 for the relation between frame rate and measurement noise normalized to the default frame rate of 25 Hz.

- Precision also scales with pulse length (the shorter the pulses, the smaller the error), but short pulses also degrade the
  detection limit due to the additional noise of the larger bandwidth.
- The influence of ambient light can be efficiently compensated; however, the remaining additional shot noise degrades both the detection limit and the repeatability error.

To achieve optimum precision values, the APD gain, the integration depth, and the laser modulation current are automatically adjusted by the ToF driver software according to the current illumination conditions.

If not otherwise specified, the following charts indicate measurements on a plane target with a size bigger than the spot size at each condition.

**NOTE:** In the near infrared, most objects show different (often higher) remission values than in the visible range. Objects that appear deep black in the visible spectrum can easily have a remission value of 10% or higher in the 850-nm wavelength range.

### **Characterization Graphs**

Figure 8: Typical Precision [mm] over Distance [m] – 1 klx, Short Range Mode



## Figure 10: Typical Precision [mm] over Distance [m] – 50 klx, Short Range Mode





## Figure 12: Typical Maximum Range [m] over Ambient Light [klx], Short Range Mode



AFBR-S50MV85G: Maximum Range [m] over Ambient Light [klx]

## Figure 9: Typical Precision [mm] over Distance [m] – 10 klx, Short Range Mode



Figure 11: Typical Precision [mm] over Distance [m] – 100 klx, Short Range Mode





Figure 13: Typical Maximum Range [m] over Ambient Light [klx] and Target Size, Short Range Mode



AFBR-S50MV85G: Maximum Range [m] over Ambient Light [klx] at 18% Remission of an Object

## Figure 14: Typical Precision [mm] over Distance [m] – 1 klx, Long Range Mode



Figure 16: Typical Precision [mm] over Distance [m] – 50 klx, Long Range Mode





Figure 18: Typical Maximum Range [m] over Ambient Light [klx], Long Range Mode



AFBR-S50MV85G: Maximum Range [m] over Ambient Light [klx]

## Figure 15: Typical Precision [mm] over Distance [m] – 10 klx, Long Range Mode



Figure 17: Typical Precision [mm] over Distance [m] – 100 klx, Long Range Mode



Figure 19: Typical Maximum Range [m] over Ambient Light [klx] and Target Size, Long Range Mode



AFBR-S50MV85G: Maximum Range [m] over Ambient Light [klx] at 18% Remission of an Object

## Figure 20: Typical Measurement Noise Factor over Frame Rate [Hz]

#### Figure 21: Typical Spot Diameter [mm] over Distance [m]





## **Digital Interface Characteristics**

Register access is performed with a standard four-wire serial peripheral interface (SPI), which is available in all common microcontrollers. It can be run with up to a 25-MHz clock frequency.

The default mode is SPI Mode 3, which translates into clock polarity CPOL = 1 (base value of clock is high) and clock phase CPHA = 1 (data output on falling edge; data is captured on rising edge). The chunk size is 8 bits (8 address bits, multiples of 8 data bits), and the endianness is big endian (most significant bit first). The timing relations are sketched in the following diagram.

#### Figure 22: SPI Timing Diagram



### **SPI Slave Interface Timing Parameters**

Description	Symbol	Min.	Тур.	Max.	Units	Notes
SPI clock frequency	f <sub>SPI</sub>	1	12	25	MHz	—
Input logic low hysteresis	V <sub>IL</sub>	—	—	1	V	—
Input logic high hysteresis	V <sub>IH</sub>	2.18			V	—
Output rise time	t <sub>rO</sub>	—	_	9	ns	1-pF load
Output fall time	t <sub>fO</sub>	—		2.1	ns	10-pF load
Output low strength	I <sub>sLO</sub>	13.5			mA	V <sub>o</sub> = 0.8V
Output high strength	I <sub>sHO</sub>	2.5			mA	V <sub>o</sub> = 2.4V
Chip select set time	t <sub>setCS</sub>	—	20	_	ns	—
Chip select hold time	t <sub>holdCS</sub>	—	20		ns	—
Data input set time	t <sub>setSI</sub>	—	15		ns	—
Data input hold time	t <sub>holdSI</sub>	—	15	_	ns	
Data output enable time	t <sub>enSO</sub>	1.7			ns	—
Data output disable time	t <sub>disSO</sub>			18.6	ns	

### **Application Circuit and Layout Recommendations**

The ToF sensor module requires local power supply filtering to limit voltage ripple based on dynamic variations of current consumption and the respective noise coupling into the module, as well as coupling back into the application circuit using the supply rails VDD and VDDL. The main noise source is the laser driver, which generates pulses in the order of 50 mA for a few nanosecond lengths, mainly drawn from the VDDL supply rail. The respective noisy GND is denoted as GNDL. The short pulses should be buffered with a 100-nF ceramic capacitor placed close to the VDDL and the GNDL pin with a sufficiently high-frequency response (impedance of less than  $0.5\Omega$  between 10 MHz and 200 MHz, such as in the X7R type in a 0603 SMD package). Because the pulses are grouped into bursts, another larger capacitor referenced to GNDL should be used to stabilize the supply, followed by a bead and another  $10-\mu$ F capacitor referenced to GND (pi filter) to block noise in both directions. At this point VDD and VDDL can be combined on the PCB to a single 5V supply rail. Since both VDD and VDDL must be noise filtered, both supply pins should be buffered against GND with a 100-nF capacitor. Additionally, the GNDL can be directly connected to a highly conductive GND plane.

There is no need to place an external oscillator, coils, or other active components except for a microcontroller unit (MCU) for module configuration and data processing. Shortcuts with the conductive ring at the pin head must be avoided. The following images show an example schematic for the application board integration and layout proposal based on a two-layer application PCB.



#### Figure 23: Application Schematic

Figure 24: Application Layout (Top Layer of a Two-Layer PCB Design)



## **Driver Software and Software Development Kit Overview**

The driver software contains all necessary parts for the sensor operation within a low-cost embedded system. It controls the laser, evaluates distances and infrared amplitudes, regulates integration times, calibrates absolute distances and temperature effects, and chooses the optimal pixels depending on the application (either distance measurement or multipixel applications).

The module software package, containing the driver software core binaries including the API layers as well as example applications, is provided free-of-charge under a generic end-user license agreement. The core binaries are embedded in a reference application that runs on the NXP/Freescale KL46Z, Cortex-M0+ platform. The reference application is distributed under the open source GNU GPL license. The driver software was developed with a focus on portability to any low-power Arm Cortex-M, 32-bit-based operation-system-less microcontroller platform. All calculations are based on fixed-point arithmetic, and no floating point unit is required.

In addition, a Windows GUI software is provided for evaluation and graphical display of measurement results, as well as easy configuration management. The GUI connects to the reference application using a generic systems communication interface (SCI) that sends and receives data packages over a USB connection. For a detailed description, refer to the API reference manual supplied with each software release.



#### Figure 25: Driver Software Block Diagram

This diagram shows the software architecture overview for the basic implementation of the ToF driver core into user hardware and software. The precompiled core is embedded into open source API layers, providing an interface to the user application. A hardware interface declares the required hardware access for the ToF driver core to the underlying hardware and peripherals. The latter is required to connect the core to the AFBR-S50 ToF sensor hardware using SPI and GPIO interfaces.

The ToF driver core provides functionality to take care of device control and communication, sensor calibrations, and measurement data evaluations. The API layers surrounding the core provide user and hardware interfaces to access the core from the application code and drive the required peripherals, respectively. The ToF driver core and API are implemented hardware independent and can be ported to any Cortex-Mx-based microcontroller platform.

The ToF driver core is designed as an interrupt-driven architecture. This allows operating the device in the background while concurrently executing heavy evaluation functionality in the foreground. No operation system is required because the background task is executed directly in the interrupt callbacks. The callbacks executed from the interrupt service routines are kept small in order to not result in a delayed or stalled system.

The device measurement cycle is triggered either by a periodic interrupt timer (PIT) or by a user call to the corresponding asynchronous API function. The core manages and updates the device configuration dynamically to adapt to changing ambient situations (distance, reflectivity, background light, temperature, and so on) and trigger the device measurement cycle afterwards. After the measurement cycle has been performed autonomously on the chip, the raw data is read and the user application is informed by invoking a callback.

To avoid loading the interrupt service routines with a heavy workload, the user application must call the evaluation and calibration task from the foreground or main thread to perform calculations and obtain calibrated measurement results like range-per-pixel in meter units. This can be done by calling the evaluation task function from a simple main loop, using a basic preemptive task scheduler or even a real-time operation system (RTOS). The core separates the measurement cycle into two main tasks:

- 1. The device communication with the ToF hardware is performed using a standard SPI interface plus a single IRQ line to obtain the data ready event. The communication is fully automated in the background within small interrupt service routines. The only action the user application might need to take is on the trigger of a new measurement cycle. This can also be done from a periodic interrupt timer. The device is dynamically updated with new configuration parameters (obtained by evaluation of the previous results or user request) before the measurement data acquisition is started. After the measurement cycle is finished, the pending IRQ from the device initiates the data read-out, and a callback function is invoked to inform the user application of the data ready event.
- 2. The data evaluation and calibration of the raw data is performed by a simple function call from the main thread to the API. Afterwards, useful information, such as range values, signal strength, or ambient light level, is available for further usage in the user application.

The following figure shows an example of the software API measurement task timing.



#### Figure 26: Software Timing Diagram

A periodic timer interrupt (PTI) triggers the measurements in the background on a time-based schedule. After the device configuration is updated, the integration cycle starts. The device acquires all measurement data autonomously and raises the measurement finished interrupt (MFI) using a GPIO line upon finishing. The data is ready to read via the SPI interface. After the SPI communication is done, the user application is informed about the new data using a callback from the SPI read done interrupt (RDI). The user application is now responsible for calling the evaluation and calibration task for the received measurement data from the foreground or main task. Meanwhile, the PTI triggers the next measurement frame independently of the current user application state.

**NOTE:** The length of the evaluation task depends on the platform and chosen algorithms, and it might be longer than the bare measurement frame time. This would lead to a delay of the measurement start and a slower frame rate.

In addition, there are several utility functions for calibration (for example, crosstalk/cover glass correction) and configuration (for example, frame rate, dynamic integration time adaption, pixel binning for 1D measurement) provided that help to achieve the best sensor performance for a vast variety of application scenarios.

To be portable, the API requires the following interfaces to peripherals, which must be implemented by the user for the platform of choice:

- SPI with GPIO Communication with the device is done using a standard four-wire SPI interface. An EEPROM is
  implemented in the chip and can be accessed via SPI pins using a not-SPI-compatible protocol that is implemented in
  software using a bit banging algorithm. Therefore, SPI pins must be accessible as GPIO pins too.
- GPIO IRQ A single GPIO interrupt input line is required for the measurement finished interrupt.
- Timer 1 (mandatory) To obey the eye-safety limits, a highly accurate and independent hardware timer is required for time measurement occasions.
- Timer 2 (optional) To maintain a fixed frame rate and trigger measurements independently in the background, an
  additional periodic interrupt timer can be used.
- Non-Volatile Memory (optional) To permanently store user calibration and configuration data, a non-volatile memory like flash might be implemented.

If the software stalls or the SPI interface is disturbed or breached, there is no risk of uncontrolled activity of the module. Because the measurement of each frame must be started by the software individually, the module will stop all activities automatically as soon as the SPI chip select is enabled, or at the latest, after the current frame measurement has been completed.

## Software and Application Support

A download link to the AFBR-S50 SDK can be found on the AFBR-S50MV85G product page:

https://www.broadcom.com/products/optical-sensors/time-of-flight-3d-sensors/AFBR-S50MV85G

Or find the Github repository here:

https://github.com/Broadcom/AFBR-S50-API

For further application or technical support topics, send an email to <a href="mailto:support.tof@broadcom.com">support.tof@broadcom.com</a> or contact your local sales representative.

## **Packaging and Ordering Information**

The modules are shipped in tubes of 60 pieces each. Including plugs, the tube length is 50 cm.

#### Figure 27: Packing Details



To check the availability and inventory at distribution channels, click the **Check Inventory** button on the AFBR-S50MV85G product page.

https://www.broadcom.com/products/optical-sensors/time-of-flight-3d-sensors/AFBR-S50MV85G

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